

DSC8004

Silicon NPN epitaxial planar type

For low frequency output amplification
Complementary to DSA8004
DSC7004 in MT-2 through hole type package

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- Contributes to miniaturization of sets, mount area reduction
- Eco-friendly Halogen-free package

■ Packaging

DSC8004×0A Radial type : 2000 pcs / carton

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	60	V
Collector-emitter voltage (Base open)	V_{CEO}	50	V
Emitter-base voltage (Collector open)	V_{EBO}	5	V
Collector current	I_C	2	A
Peak collector current	I_{CP}	3	A
Collector power dissipation *	P_C	1	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Note) *: Printed circuit board: Copper foil area of 1 cm^2 or more, and the board thickness of 1.7 mm for the collector portion

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10\ \mu\text{A}, I_E = 0$	60			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 1\ \text{mA}, I_B = 0$	50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10\ \mu\text{A}, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 20\ \text{V}, I_E = 0$			0.1	μA
Forward current transfer ratio *1	h_{FE1} *2	$V_{CE} = 2\ \text{V}, I_C = 200\ \text{mA}$	120		340	—
	h_{FE2}	$V_{CE} = 2\ \text{V}, I_C = 1\ \text{A}$	80			
Collector-emitter saturation voltage *1	$V_{CE(sat)}$	$I_C = 1\ \text{A}, I_B = 50\ \text{mA}$		0.15	0.3	V
Base-emitter saturation voltage *1	$V_{BE(sat)}$	$I_C = 1\ \text{A}, I_B = 50\ \text{mA}$		0.9	1.2	V
Transition frequency	f_T	$V_{CE} = 10\ \text{V}, I_C = 50\ \text{mA}$		120		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = 10\ \text{V}, I_E = 0, f = 1\ \text{MHz}$		22	35	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

Code	R	S	0
Rank	R	S	No-rank
h_{FE1}	120 to 240	170 to 340	120 to 340
Marking Symbol	5BR	5BS	5B

Product of no-rank is not classified and have no marking symbol for rank.

■ Package

• Code

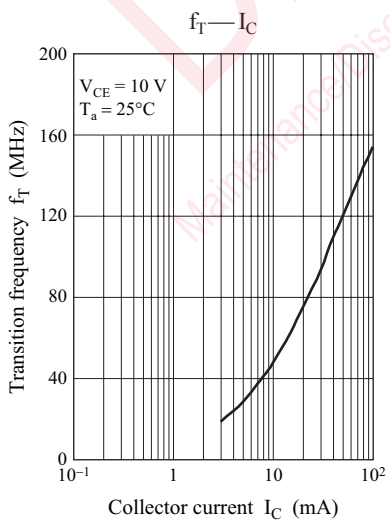
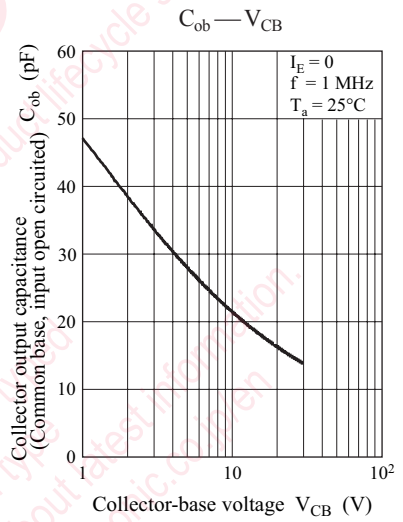
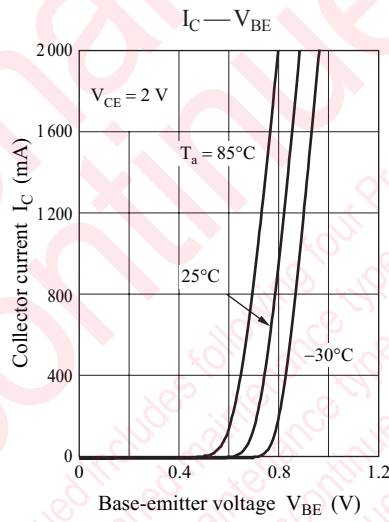
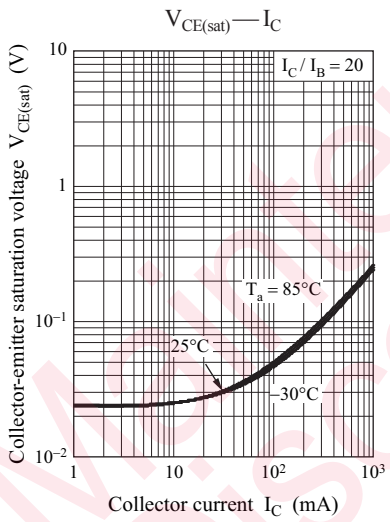
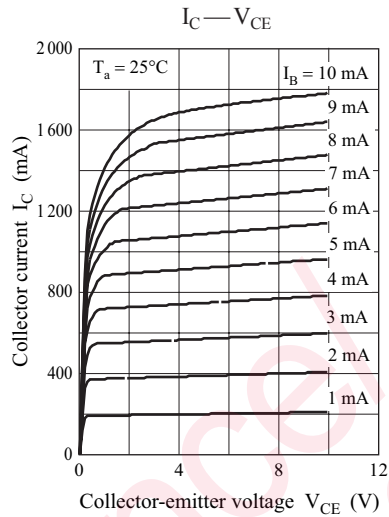
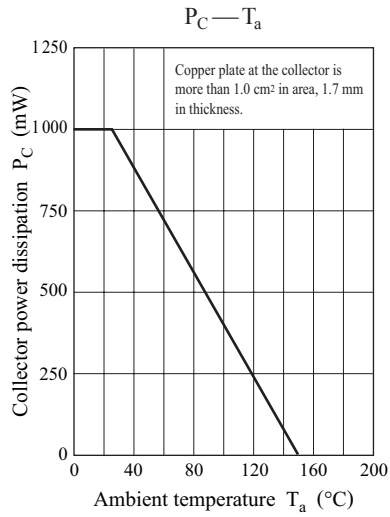
MT-2-A2-B

Package dimension clicks here.→

• Pin Name

1. Emitter
2. Collector
3. Base

■ Marking Symbol: 5B



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